NAND Flash-based Solid State Drive

Standard Type GT series
Product Specification

Version 1.0
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Revision History

Revision No	History	Draft Date	Remark
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0.1	Performance data updated	Sept. 9, 2008	Preliminary
1.0	Performance update	Oct. 20, 2008	Formal

The attached data sheets are prepared and approved by MemoRight. And MemoRight has the right to change all the specifications in data sheets. MemoRight will evaluate and reply to any dear customer‘s requests and questions on the parameters of this device. If dear customer has any questions, please call or fax to MemoRight headquarters, or contact the MemoRight branch office near your office.

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1. General Description

The NSSD (NAND Flash-based Solid State Drives) of MemoRight consists of semiconductor devices completely, and the storage media is NAND Flash which has high reliability and high compatibility.

As the NSSD doesn't have any mechanical part such as platter (disk), motor and suspension, it gives a good solution in a UMPC and Tablet PC for a storage device with high performance and low power consumption and small form factor.

At the same time it gives rugged feature in industrial PC with an extreme environment and an increased MTBF.

For an easy adoption, the NSSD has the same device interface and physical dimension with HDD.

1.1 Density

32GBytes, 64GBytes, 128GBytes

1.2 Form Factor

2.5" Type (100.20 x 69.85 x 9.50)mm

1.3 Host interface

PIO Mode 0 to 4
UDMA Mode 0 to 6
Serial ATA 1.0a specification

1.4 Performance

Host Interface: Max 150MB/s
Sustained Read transfer: Max 120MB/s (100MB/s for 128GB)
Sustained Write transfer: Max 120MB/s (100MB/s for 128GB)
Access time: < 0.1ms
Random IOPS Read @512Bytes: 10,000（9600 for 128GB）
Random IOPS Write@512Bytes: 600(500 for 128GB)

1.5 Reliability

1.5.1 Wear Leveling

This drive uses dynamic, static and active (initiative) balanced wear leveling strategy, which will ensure that all blocks have nearly same wear level, and reduce the dependence of the write endurance on access pattern.

1.5.2 Endurance

Write endurance: >10 years @ 1TByte/day (64GB type)

Read endurance: unlimited

1.5.3 ECC

This drive also implements an enhanced ECC algorithm, which reduces the error rate and enforces the write endurance at same time. 4-bit error correction per sector(512 Bytes).

1.5.4 Bad block management algorithm

This drive has a certain number of reserved blocks. When a user data block fails, a reserved block will replace the failed block. The replacement of bad block is transparent to user.

1.5.5 MTBF(Mean Time between Failures)

More than 1,100,000 hours (32GB typical)

Calculation model: Telcordia SR-332 Issue 1 Method 1, Case 1

1.5.6 Data Retention

Data retention :>10 years
Test under room temperature.

1.6 Power consumption

Input voltage: +5VDC, ±5%(4.75V ~ 5.25V)
Continue write : Typical 400mA
Continue read : Typical 400mA
Idle : Typical 200mA
Standby : Typical 200mA
Test under room temperature @ 5V

1.7 Environmental

1.7.1 Temperature

Operating : 0'C ~ 70'C(Commercial)
Non-Operation: -40'C ~ 85'C

1.7.2 Shock

Operating: 50G, duration 11ms, Half Sine Wave

Non-Operating: 1500G, duration 0.5ms, Half Sine Wave

1.7.3 Vibration

Operating: 16.4G Peak, 10~2000Hz, x3 Axis

1.8 NSSD Functional Block Diagram

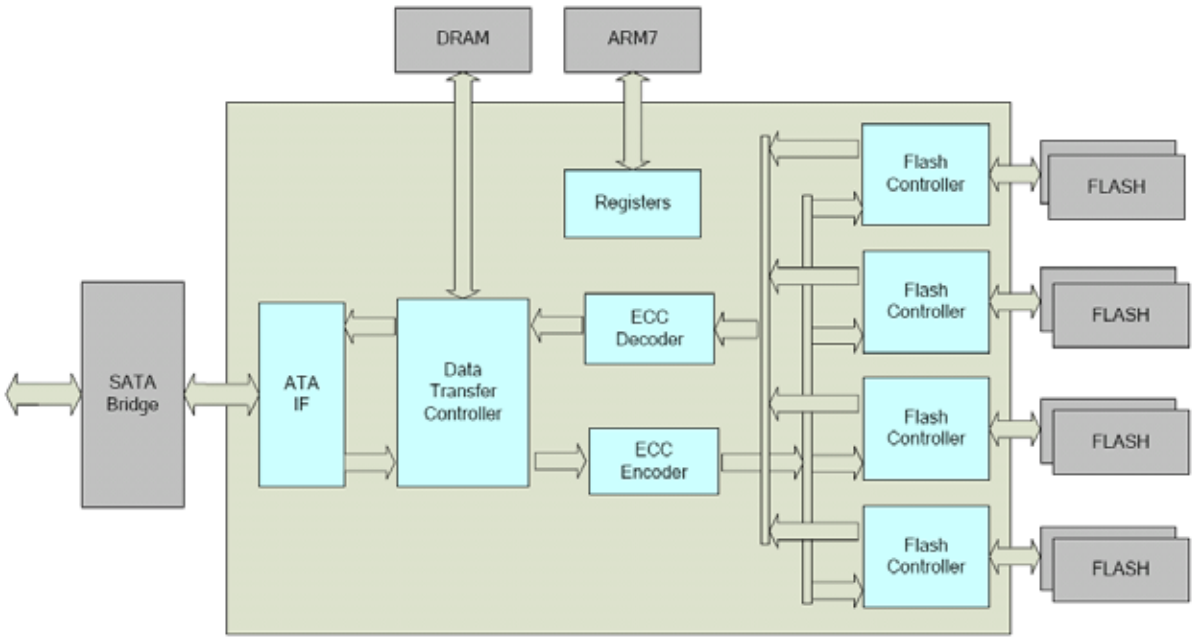

Figure 1. NSSD Functional Block Diagram

2 Physical specifications

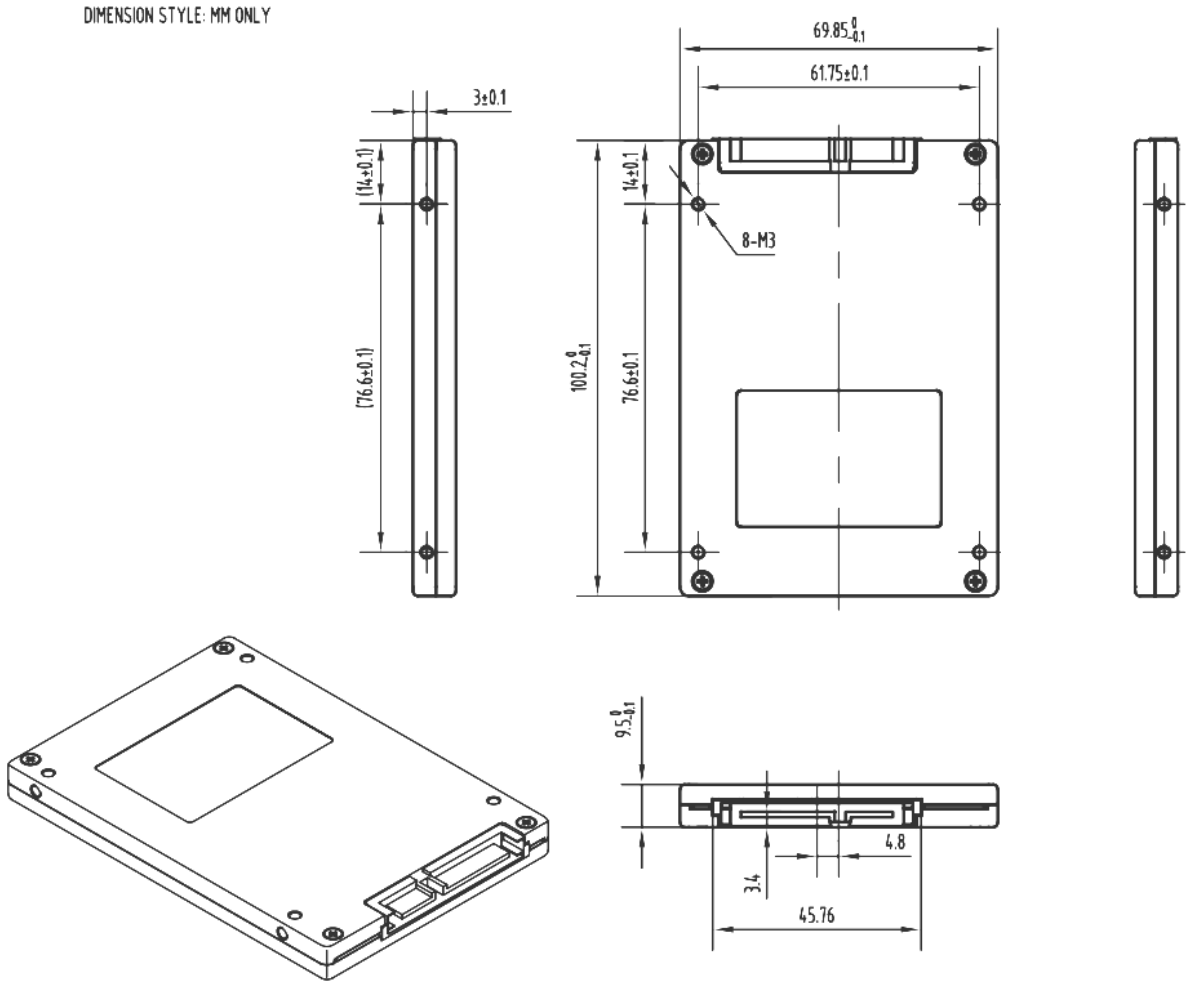

Figure 2. Physical specifications

3 Drive Specifications

Unless otherwise noted, all specifications are measured under ambient conditions, at 25°C, and nominal power. For convenience, the phrases of the drives used throughout this manual are indicated the following drive models:

MR25.2-032S
MR25.2-064S
MR25.2-128S

3.1 Specification Summary table

The specifications listed in the table below are for quick reference. For details on specification measurement or definition, see the appropriate section of this manual.

Table 1: Specifications Summary

Drive specification	MR25.2-032S	MR25.2-064S	MR25.2-128S
Unformatted capacity	32GB *	64GB *	128GB *
Guaranteed sectors	62,914,560	125,829,120	251,658,240
Sustained data transfer rate(read)	120 Mbytes/sec	120 Mbytes/sec	100 Mbytes/sec
Sustained data transfer rate(write)	120 Mbytes/sec	120 Mbytes/sec	100 Mbytes/sec
Channels	4		
Media type	Single Layer Cell (SLC) NAND Flash		
Random 512Byte IOPS(read)	10,000	10,000	9600
Random 512Byte IOPS(write)	600	600	500
Interface	Serial ATA 1.0a		
I/O data-transfer rate	150 Mbytes/sec		
ATA data-transfer modes supported	PIO modes 0-4, Ultra DMA modes 0-6		
Cache buffer	32 Mbytes		
Height	$9.5\ ^{0}_{-0.1}$ mm ($0.374\ ^{0}_{-0.004}$ inches)		
width	$69.85\ ^{0}_{-0.1}$ mm ($2.75\ ^{0}_{-0.004}$ inches)		
Length	$100.5\ ^{0}_{-0.1}$ mm ($3.96\ ^{0}_{-0.004}$ inches)		
Weight(grams)	78.0 ± 5.0		88.0 ± 5.0
Average latency(Typical)	$<$0.1 msec		
Power-on to ready(Typical)	1 sec		
Standby to ready(Typical)	0.1 sec		
Warm-up current (Typical)* *	0.75 amps		
Continue read power(Typical) * *	2.0 watts		
Continue write power (Typical)* *	2.0 watts		
Idle mode power(Typical) * *	1 watts		
Standby mode power(Typical) * *	1 watts		
Sleep mode power(Typical)* *	1 watts		
Voltage tolerance (including noise)	5V ± 5%		
Ambient temperature	0° to 70°C (operating)		
	–40° to 85°C (non-operating)		
Temperature gradient	20°C (operating)		

(°C per hour max, non-condensing)	30°C (non-operating)
Humidity (non-condensing)	50%,95% (operating)
Relative humidity gradient	30% per hour max
Drive acoustics, sound power (dB)	0
Non-recoverable read errors	< 1 per 10^{14} bits read
Mean Time Before Failure (MTBF)	More than 1,100,000 hours (32GB typical) Calculation model: Telcordia SR-332 Issue 1 Method 1, Case 1
Altitude	0-80000(Ft) / 0-24(km.)
Service life	5 Years
Warranty* * *	5 Years

* 1GB = 1,000,000,000 Bytes
* * typical value under room temperature
* * * three-years free warranty and two-years paid maintenance.

3.2 Unformatted capacity

Table 2: Products capacity

Model	Unformatted capacity	Guaranteed sectors	Bytes per sector
MR25.2-032S	32 GBytes	62,914,560	512
MR25.2-064S	64 GBytes	125,829,120	512
MR25.2-128S	128 GBytes	251,658,240	512

3.3 Default logic geometry

Table 3:Default logic geometry

Cylinders	Read/write heads	Sectors per track
16383	16	63

LBA mode

When addressing these drives in LBA mode, all blocks (sectors) are consecutively numbered from 0 to n–1, where n is the number of guaranteed sectors as defined above.

3.4 Physical organization

Table 4:Physical organization

Model	Channels
MR25.2-032S	4
MR25.2-064S	4
MR25.2-128S	4

The number of channels means the maximum NAND flash units parallel involved in each host command execution.

3.5 Recording and interface technology

Table 5: Recording and interface

Technology	Specification
Interface	Serial ATA 1.0a
Interface data transfer rate (Mbytes/sec max)	150(SATA 1.0a)
Recording media	Single Layer Cell(SLC) NAND flash
Cache buffer	32 Mbytes

3.6 Physical characteristics

Table 6: Physical characteristics

Height	(mm)	$9.5\ ^{0}_{-0.1}$
	(inches)	$0.374\ ^{0}_{-0.004}$
Width	(mm)	$69.85\ ^{0}_{-0.1}$
	(inches)	$2.75\ ^{0}_{-0.004}$
Length	(mm)	$100.5\ ^{0}_{-0.1}$
	(inches)	$3.96\ ^{0}_{-0.004}$
Typical weigtht	(grams)	78.0±5.0(32G & 64G) /88.0±5.0(128G)
	(pounds)	0.172±0.011(32G & 64G) /0.194±0.011(128G)

3.7 Access time

Table 7：Access time

	Access time
Read(cache hit), typical	0.04 msec
Read(cache miss), typical	0.08 msec
Write(cache hit or cache non-full), typical	0.04 msec
Write(cache miss and cache full), typical	2 msec

The time accessing to data in HDD equals to that the seek time plus the latency time, not including controller time overhead. But for SSD, the latency time is 0, and the seek time is very small. Most of the time is consumed by controller overhead.

The access time definition here is measured from the last byte of host command received by drive to the first data byte sent to host by drive in read operation.

Notes for Section 3.7

*Assumes that no error and no sector is relocated.
* *Assumes that system ability supports the UDMA-6.

3.8 Performance characteristics

The performance test results are based on environments as below:

Mother Board: GIGBYTE X38-DQ6
CPU: E8400 3.00GHz
Chipset: Intel X38 + ICH9R
Graphic: NVIDIA6200LE
RAM: Kingston 2GB DUAL channel DDR2-800
BIOS: Award/6.00PG/F7
OS: Windows XP pro sp2
Test software: IOMeter 2006.07.27
SSD: MR25.2-032S (FW: B8J22D1F)
/MR25.2-064S(FW: B8J22D1F)
/MR25.2-128S (FW: B8J22D4F)
Test sustaining time: Five minutes

Table 8:Performance characteristics

SSD	MR25.2-032S/ MR25.2-064S		
Test item	**Request size**	**Throughput(MBytes/sec)**	**IOPS**
Consecutive read(typical)	0.5KBytes	8.76	17,941
	4 KBytes	37.88	9,697
	8 KBytes	51.21	6,555
	64KBytes	112.79	1,805
	128 KBytes	118.05	944
Consecutive write(typical)	0.5KBytes	9.14	18,724
	4 KBytes	54.87	14,047
	8 KBytes	78.42	10,037
	64KBytes	122.81	1,965
	128 KBytes	126.53	1,012
Random read(typical)	0.5KBytes	5.11	10,475
	4 KBytes	23.62	6,046
	8 KBytes	37.81	4,839
	64KBytes	96.27	1,540
	128 KBytes	108.33	867
Random write(typical)	0.5KBytes	0.32	650
	4 KBytes	1.42	364
	8 KBytes	1.89	242
	64KBytes	10.32	165
	128 KBytes	19.34	155
SSD	**MR25.2-128S**		
Test item	**Request size**	**Throughput(MBytes/sec)**	**IOPS**
Consecutive read(typical)	0.5KBytes	8.21	16,816
	4 KBytes	34.29	8,779

	8 KBytes	45.97	5,884
	64KBytes	97.19	1,555
	128 KBytes	101.34	811
Consecutive write(typical)	0.5KBytes	8.42	17,238
	4 KBytes	52.09	13,336
	8 KBytes	75.35	9,645
	64KBytes	104.04	1,665
	128 KBytes	104.01	832
Random read(typical)	0.5KBytes	4.72	9,675
	4 KBytes	20.80	5,325
	8 KBytes	33.10	4,236
	64KBytes	83.73	1,340
	128 KBytes	93.40	747
Random write(typical)	0.5KBytes	0.30	605
	4 KBytes	1.33	341
	8 KBytes	1.78	228
	64KBytes	9.77	156
	128 KBytes	17.60	141

3.9 Start/stop time

Table 9:Start/stop time

Time to ready	Typical(sec)	Max(sec)
Power-on to ready	1	10
Warm-up time	5	10
Standby to ready	0.1	0.1
Power-off to power-on	1	/
Power-off to cache flush done	0.1	1

The MemoRight's NSSD have an on-drive backup power system. It saves energy when the power supply is applied to drive. When power-off occurring, the saved energy will be released to keep the drive working for a while. The saved energy ensures the data in the cache can be flushed to the nonvolatile flash media, which prevents the data loss to happen.

It will take about 5 seconds to save enough energy for discharge at lease 1 second. The write cache will be disabled automatically before the backup power system saved enough energy.

The cycle number of the backup power system is at lease 300,000 to ensure covering the lifespan of the drive.

3.10 Write endurance

The write endurance is mostly depending on the write model since each write to flash will cause an erase operation of the data block. Consecutive write will be better than random write, and large date block will be better than small data block.

Table 10:Write endurance

	Request size	TBytes/GBytes	IO/GBytes
Consecutive write	2 KBytes	>100	$>5\times10^{10}$
	16 KBytes	>100	$>6.3\times10^{9}$
	128 KBytes	>100	$>7.8\times10^{8}$
Random	2 KBytes	>1.6	$>8\times10^{8}$

write(100% cache miss)	16 KBytes	>3.2	>2×10^8
	128 KBytes	>25	>2×10^8

In actual application environments, since this drive have a 32MByte cache and the cache strategy fine tuned for NAND flash, the write endurance will exceed this specification in almost all situation.

3.11 Power specifications

The drive receives DC power (+5V) through the interface connector.

3.11.1 Power consumption

Power requirement for the drive is listed in the table. Typical power measurements are based on an average of drive testing, under nominal conditions, using 5.0V input voltage at room temperature.

- **Warm-up power**

Warm-up power is measured from the time of power-on to the time that the drive's back up power system has stored enough energy.

- **Read power**

The read power is measured with three 63 sectors read operations every 100msecs.

The consecutive read power is measured with consecutive 128Kbytes read operations.

- **Write power**

The write power is measured with three 63 sectors write operations every 100msecs.

The consecutive write power is measured with consecutive 128Kbytes write operations.

- **Idle mode power**

The idle power is measured with no read/wrote operation.

- **Standby mode power**

During Standby mode, the drive accepts commands, and the DRAM cache is in sleep mode and the MCU is running in slower clock.

Table 11:Power Consumption

Power mode	Power consumption(watts) (+5V, Room Temp)
Warm-up	3.75
Read	1.0
Consecutive read	2.0
Write	1.0
Consecutive write	2.0
Idle	1.0
Standby	1.0

3.11.2 Conducted Noise

Input noise ripple is measured at the host system power supply across an equivalent 25-ohm resistive loading on the +5 volt line.

Using 5-volt power, the drive is expected to operate with a maximum of 100 mV peak-to-peak square-wave injected noise at up to 10 MHz.

Note: Equivalent resistance is calculated by dividing the nominal voltage by the typical RMS read/write current.

3.11.3 Voltage tolerance

Voltage tolerance (including noise):

5V ± 5%

3.12 Environmental specifications

3.12.1 Ambient temperature

Ambient temperature is defined as the temperature of the environment immediately surrounding the drive. Actual drives usual temperature should not exceed 70°C (158°F) within the operating ambient conditions.

Above 1,000 feet (305 meters), the maximum temperature is decreased linearly by 1°C every 1000 feet.

Table 12: Ambient temperature

Operating	0° to 70°C (32°F to 158°F)
Non-operating	–40° to 85°C (–40°F to 185°F)

3.12.2 Acoustics

Because of the complete chip configuration, outside noise has no influence on NSSD.

3.12.3 Electromagnetic immunity

The recording medium of traditional HDD is magnetic material, and the head is sensitive to environmental magnetic field. However the NSSD's recording medium is NAND Flash, which is a kind of semiconductor based on silicon. Go without saying, NSSD isn't affected by electromagnetic field.

3.12.4 Gravitation

NSSD products have extensive applications. They can be used in some special environment such as zero gravity. Because the NSSD is made of full chip, the gravitation has no effect on it.

3.12.5 Medium

NSSD products haven't any mechanical configuration inside. There is almost no requirement for medium. It is possible that NSSD products work under the condition of vacuum or liquid.

3.13 Reliability

It's well known that the reliability of a chip configuration is better than a mechanical configuration. Because the mechanical configuration is affected by too many factors, it influences the reliability of HDD very much. While the chip configuration is opposite, it makes that NSSD has a nice reliability.

3.14 Agency certification

NSSD products have passed the following agency certification: FCC 、CE, C-TICK, UL, CUL.

3.15 Environmental protection

NSSD produces almost no quantity of heat and the noise is 0 dB when it is working. At the same time, the NSSD products and the enclosed components/devices and/or assemblies are lead-free. It has no influence on environment.

4 Configuring and mounting the drive

This section contains the specifications and the instructions for configuring and mounting the drive.

4.1 Static discharge and handling precautions

After unpacking and before installation, the drive may be exposed to potential handling and electrostatic discharge (ESD) hazards. Observe the following standard handling and static-discharge precautions:

Caution:

- Keep the drive in the electrostatic discharge (ESD) bag until you are ready to installation to limit the drive's exposure to ESD.
- Before handling the drive, put on a grounded wrist strap, or ground yourself frequently by touching the metal chassis of a computer that is plugged into a grounded outlet. Wear a grounded wrist strap throughout the entire installation procedure.
- Handle the drive only by its edges or frame.
- The drive is fragile, and handles it with care. Do not press down on the drive top cover.
- Always rest the drive on a padded, antistatic surface until you mount it in the computer.
- Do not touch the connector pins or the printed circuit board.
- Do not remove the factory-installed labels from the drive or cover them with additional labels. Removal voids the warranty. Some factory-installed labels contain information needed to service the drive. Other labels are used to seal out dirt and contamination.

4.2 Drive mounting

You can mount the drive using four screws in the side-mounting holes or four screws in the bottom-mounting holes. See Figure 2 for drive mounting dimensions (dimensions in inches with mm in parentheses). Follow these important mounting precautions when mounting the drive:

- Allow a minimum clearance of 0.030 inches (0.76 mm) around the entire perimeter of the drive for cooling.
- Use only M3 x 6mounting screws.
- Do not over tighten the mounting screws (maximum torque: 5.0 inch-lb).
- Four (4) threads (0.080 inches) minimum screw engagement recommended.

4.3 Installation considerations

The advantages of NSSD are obvious comparing to HDD. More and more users of computers replace the hard drive with NSSD, or planning to do so. Refer to your system's user manual for the location of the hard drive compartment and the specific instructions regarding replacement. Refer to your system manufacturer's support website for the most up-to-date information. Read and follow all instructions regarding the proper steps to be taken when replacing the system hard drive. Some mobile systems are sealed and require specialized tools to gain access to the hard drive. Special training or tools may be needed to service some mobile computers. In some cases, opening the case may void your warranty. Consult your system documentation. MemoRight recommends taking your system to an authorized service technician to replace your hard drive.

- Unpack the drive and keep it away from any potential ESD (Electrostatic Discharge) hazard area.
- Mount the drive with 4 screws either through the two sides of the drive or at the bottom of the drive.
- Use M3 x 6mm screws which you may find in the packing box.
- Connect the 15-Pin power cable to the power connector of the drive and connect the 7-Pin signal cable to the signal connector of the drive properly.

- Power on your host and then format the SSD or initiate the SSD through the RAID card with the standard drive format procedure.
- Please install the windows XP first then Vista if coexisted systems required.

5 SATA interface

The drive uses the industry-standard Serial ATA interface that supports 16-bit data transfers. It supports programmed input/output (PIO) modes 0–4; Ultra DMA modes 0–6. The drive also supports the use of the IORDY signal to provide reliable high-speed data transfers.

For detailed information about the Serial ATA interface, refer to the draft of AT Attachment with Packet Interface Extension (ATA/ATAPI-7), NCITS T13 1410D, subsequently referred to as the Draft ATA-7 Standard.

5.1 SATA interface signals and connector pins

The connector on MemoRight SATA NSSD is divided into a signal Segment and a power Segment. The following tables summarizes the signals on the SATA interface connector. For a detailed description of these signals, refer to the Draft ATA-7 Standard.

5.1.1 Signal Segment Pin-out Configuration

Pin Configuration

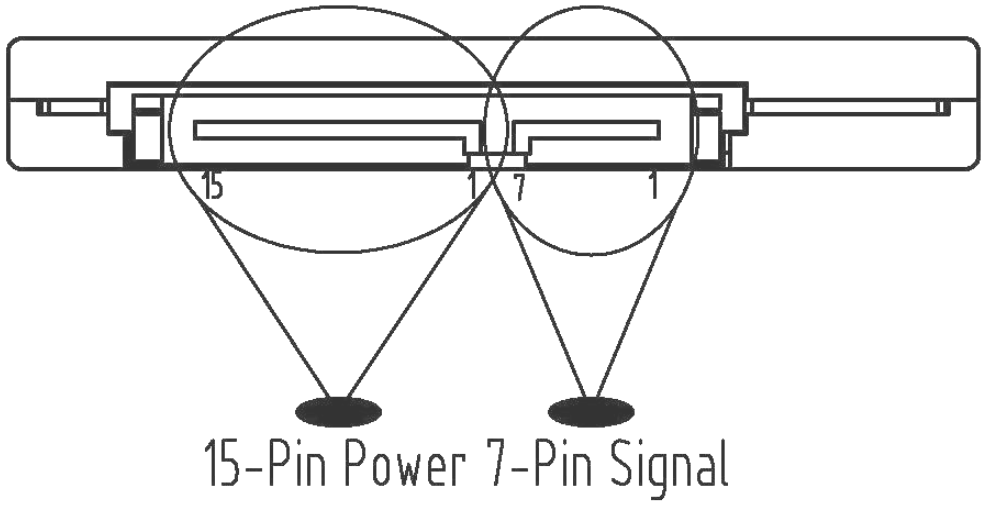

Figure 3. Memoright SATA Connector View

The SATA signal cable uses a protocol transmitted over a 7-pin cable. The following table lists the signal definitions of the 7-pin segment.

Table 13:SATA Connector Signal Definitions

Pin	Signal Name	Signal Definitions
S1	Ground	Second Mate
S2	R+	+Differential Receive Signal
S3	R-	-Differential Receive Signal
S4	Ground	Second Mate
S5	T-	-Differential Transmit Signal
S6	T+	+Differential Transmit Signal
S7	Ground	Second Mate

5.1.2 Power Segment Pin-out Configuration

The SATA power connector consists of 15 pins. The following table lists the signal definitions of the

15-pin segment.

Table 14:SATA Connector Power segment Definitions

Pin	Signal Name	Signal Definitions
P1	V3.3	3.3V Power(Not used)
P2	V3.3	3.3V Power(Not used)
P3	V3.3	3.3V Power(Not used)
P4	Ground	First Mate
P5	Ground	Second Mate
P6	Ground	Second Mate
P7	V5	5V Power, pre-charge, Second Mate
P8	V5	5V Power
P9	V5	5V Power
P10	Ground	Second Mate
P11	Reserved	Reserved
P12	Ground	First Mate
P13	V12	12V Power(Not used)
P14	V12	12V Power(Not used)
P15	V12	12V Power(Not used)

5.2 Supported ATA commands

The following table lists ATA-standard commands supported by MemoRight SATA NSSD. For a detailed description of the ATA commands, refer to the Draft ATA-7 Standard.

Table 15:Supported ATA commands

Command name	Controller(in hex)
ATA-standard commands	
Recalibrate	10h
Read Sectors	20h
Write Sectors	30h
Read Verify Sectors	40h
Seek	70h
Execute Device Diagnostic	90h
Initialize Device Parameters	91h
S.M.A.R.T.	B0h
Read Multiple	C4h
Write Multiple	C5h
Set Multiple Mode	C6h
Read DMA	C8h
Write DMA	CAh
Read Buffer	E4h
Flush Cache	E7h
Write Buffer	E8h
Identify Device	ECh
Set Features	EFh
ATA-standard power-management commands	
Check Power Mode	98h, E5h

Sleep	E6h
Standby Immediate	E0h
Idle Immediate	95h, E1h
Standby	E2h
Idle	97h, E3h
ATA 48bit address commands	
Read Sector(s) EXT	24h
Read DMA EXT	25h
Read Multiple EXT	29h
Write Sector(s) EXT	34h
Write DMA EXT	35h
Write Multiple EXT	39h
Read Verify Sector(s) EXT	42h
Flush CACHE EXT	EAh

5.2.1 Recalibrate (10h)

When this command is issued, the NSSD sets BSY and waits for that the device is initialized, and then clears BSY.

5.2.2 Read Sector(s) (20h)

This command will read from 1 to 256 sectors as specified in the Sector Count Register. A sector count of 0 (zero) requests 256 sectors. The transfer will begin at the sector specified in the Sector Number Register.

5.2.3 Read Sector(s) EXT (24h)

This command reads from 1 to 65,536 sectors as specified in the Sector Count register. A sector count of 0000h requests 65,536 sectors. The transfer shall begin at the sector specified in the LBA Low, LBA Mid, and LBA High registers.

5.2.4 Read DMA EXT(25h)

The Read DMA EXT command allows the host to read data using the DMA data transfer protocol.

5.2.5 Read Multiple EXT(29h)

This command reads the number of sectors specified in the Sector Count register.

5.2.6 Write Sector(s) (30h)

This command will write from 1 to 256 sectors as specified in the Sector Count Register. A sector count of 0 (zero) will request 256 sectors. The transfer begins at the sector specified in the Sector Number Register.

5.2.7 Write Sector(s) EXT(34h)

This command reads the number of sectors specified in the Sector Count register.

5.2.8 Write DMA EXT(35h)

The Write DMA EXT command allows the host to write data using the DMA data transfer protocol.

5.2.9 Write Multiple EXT(39h)

This command writes the number of sectors specified in the Sector Count register.

5.2.10 Read/Verify Sector(s) (40h)

This command will verify one or more sectors by transferring data from the flash media to the data buffer and verifying the ECC is correct. The command is identical to the Read Sector(s) - 20h command except that DRQ is never set and no data is transferred to the host.

5.2.11 Read Verify Sector(s) EXT(42h)

This command is identical to the Read Sector(s) EXT command, except that the device shall have read the data from the media, the DRQ bit is never set to one, and no data is transferred to the host.

5.2.12 Seek (70h)

This command will cause the device performing a range check.

5.2.13 Execute Device Diagnostic (90h)

This command performs the internal diagnostic tests implemented by the controller.

5.2.14 Initialize Device Parameters (91h)

This command will enable the host to set the number of sectors per track and the number of heads per cylinder.

5.2.15 S.M.A.R.T (B0h)

When this command is issued, the NSSD will report the SMART data to Host.

5.2.16 Read Multiple (C4h)

This command is similar to the Read Sector(s) -20h command. Interrupts are not generated on each sector, but on the transfer of a block that contains the number of sectors as defined by a Set Multiple Mode - C6h command.

5.2.17 Write Multiple (C5h)

This command is similar to the Write Sector(s) - 30h command. Interrupts are not presented on each sector, but on the transfer of a block which contains the number of sectors defined by the Set Multiple Mode - C6h command.

5.2.18 Set Multiple Mode (C6h)

This command enables the SSD to perform multiple Read and Write operations and establishes the block count for these commands.

5.2.19 Read DMA (C8h)

When this command is issued, the SSD will prepare the data, and transfer the data to host via ultra DMA protocol.

5.2.20 Write DMA (CAh)

When this command is issued, the NSSD will prepare for receiving the data transfer from host via ultra DMA protocol.

5.2.21 Standby Immediate (E0h)

This command will cause the NSSD to set BSY, enter the Standby Mode, clear BSY, and return the interrupt immediately.

5.2.22 Idle immediate (E1h or 95h)

This command will cause the drive to set BSY, enter the IDLE (READ) mode, clear BSY, and generate an interrupt.

5.2.23 Standby (E2h)

This command is similar to Standby immediate.

5.2.24 Idle (E3h)

This command is similar to Idle immediate.

5.2.25 Read Buffer (E4h)

This command enables the NSSD to transfer the buffer data in cache.

5.2.26 Check Power (E5h or 98h)

This command enables the Host to check the NSSD power mode.

5.2.27 Sleep (E6h)

This command enables the Host set NSSD into sleep mode.

5.2.28 Flush Cache (E7h)

When this command is issued, the device will flush all data in cache into NSSD disk to protect the data.

5.2.29 Write Buffer (E8h)

This command enables the NSSD to receive the buffer data from host into cache.

5.2.30 Flush CACHE EXT(EAh)

This command is used by the host to request the device to flush the write cache. If there is data in the write cache, that data shall be written to the media. The BSY bit shall remain set to one until all data has been successfully written or an error occurs.

5.2.31 Identity Device (ECh)

The Identify Device command (command code ECH) transfers information about the drive to the host following power up. The data is organized as a single 512-byte block of data, whose contents are shown in Table 7 on page 20. All reserved bits or words should be set to zero. Parameters listed with an “x” are drive-specific or vary with the state of the drive. See Section 2.0 on page 3 for default parameter settings.

The following commands contain drive-specific features that may not be included in the Draft ATA-7 Standard.

Table 16: Drive-specific features

Word	Description	Value
0	Configuration information: Bit 15: 0=ATA; 1=ATAPI Bit 7: removable media Bit 6: removable Controller Bit 0: reserved	0040h
1	Number of logical cylinders	3FFFh
2	Specific configuration	C837h
3	Number of logical heads	0010h
4	Retired	0000h
5	Retired	0000h
6	Number of logical sectors per logical track	003Fh
7-9	Retired	0000h
10-19	Serial number: 20 ASCII characters	ASCII
20	Retired	0000h

21	Retired	0000h
22	Obsolete	0000h
23-26	Firmware revision: 8ASCII characters	ASCII
27-46	Drive model number: 40 ASCII characters	ASCII
47	(Bits 7–0) Maximum sectors per interrupt on Read multiple and Write multiple (1)	8001h
48	Reserved	0000h
49	Standard Standby timer, IORDY supported and may be disabled	2F00h
50	Capabilities	4000h
51	Retired	0000h
52	Retired	0000h
53	Words 54–58, 64–70 and 88 are valid	0007h
54	Number of current logical cylinders	XXXXh
55	Number of current logical heads	XXXXh
56	Number of current logical sectors per logical track	XXXXh
57-58	Current capacity in sectors	XXXXh
59	Multiple sector setting	0101h
60-61	Total number of user address sectors(LBA mode)	XXXX XXXXh
62	Obsolete	0000h
63	Multi-word DMA transfer(Not support)	0000h
64	Flow control PIO transfer modes supported	0003h
65	Minimum Multiword DMA transfer cycle time per word	0078h
66	Manufacturer's recommended Multiword DMA transfer cycle time per word	0078h
67	Minimum PIO transfer cycle time without flow control	0078h
68	Minimum PIO transfer cycle time with IORDY flow control	0078h
69-74	Reserved	0000h
75	No DMA QUEUED command supports	0000h
76-79	Reserved	0000h
80-81	ATA Ver support (ATA/ATAPI-7 T13 1532D revision 4a)	00FE 0021h
82	Command set supported 15 0 = Obsolete 14 1 = NOP Command supported 13 1 = READ BUFFER Command supported 12 1 = WRITE BUFFER Command supported 11 1 = Obsolete 10 0 = Host Protected Area Feature Set not supported 09 0 = DEVICE RESET Command not supported 08 0 = SERVICE Interrupt not supported 07 0 = RELEASE Interrupt not supported 06 1 = Look Ahead supported 05 1 = Write Cache supported 04 0 = indicate that the PACKET feature set not supported 03 1 = Power Management Feature Set supported (mandatory) 02 0 = Removable Media feature set not supported 01 1 = Security Mode Feature Set supported 00 1 = SMART Feature Set supported	786Bh
83	Command set supported 15 Shall be cleared to zero 14 Shall be set to one 13 0 = FLUSH CACHE EXT Command not supported 12 1 = FLUSH CACHE Command supported (mandatory)	5028h/5428h

	11 0 = Device Configuration Overlay feature set not supported 10 1/0 = 48-Bit Address feature set supported /not supported 09 0 = Automatic Acoustic Management feature set not supported 08 0 = SET MAX security extension not supported 07 0 = See Address Offset Reserved Area Boot, INCITS TR27:2001 06 0 = SET FEATURES subcommand not required to spin-up after power-up 05 1 = Power-Up in Standby feature set supported 04 0 = Obsolete 03 1 = Advanced Power Management feature set supported 02 0 = CFA feature set not supported 01 0 = READ/WRITE DMA QUEUED not supported 00 0 = DOWNLOAD MICROCODE Command not supported	
84	Command Set/Feature Supported Extension 15 Shall be cleared to zero 14 Shall be set to one 13 0 = IDLE IMMEDIATE with UNLOAD FEATURE not supported 12 0 = Reserved 11 0 = Reserved 10:9 0 = Obsolete 08 0 = 64-Bit World Wide Name not supported 07 0 = Write DMA QUEUED FUA EXT Command not supported 06 0 = Write DMA FUA EXT and WRITE MULTIPLE FUA EXT commands not supported 05 0 = General Purpose Logging feature set not supported 04 0 = Streaming feature set not supported 03 0= Media Card Pass Through Command feature set not supported 02 0 = Media Serial Number not supported 01 1 = SMART Self-Test supported 00 1 = SMART Error-Logging supported	4003h
85	Command set/feature enabled 15 0 = Obsolete 14 1 = NOP Command enabled 13 1 = READ BUFFER Command enabled 12 1 = WRITE BUFFER Command enabled 11 1 = Obsolete 10 0 = Host Protected Area has not been established 09 0 = DEVICE RESET Command not enabled 08 0 = SERVICE Interrupt not enabled 07 0 = RELEASE Interrupt not enabled 06 1 = Look Ahead enabled 05 1 = Write Cache enabled 04 0 = indicate that the PACKET feature is not supported. 03 1 = Power Management Feature Set enabled 02 0 = Obsolete 01 0 = Security Mode Feature Set enabled 00 1 = SMART Feature Set enabled	7869h
86	Command set/feature enabled 15 0 = Reserved 14 0 = Reserved 13 0 = FLUSH CACHE EXT Command not supported 12 1 = FLUSH CACHE Command supported 11 0 = Device Configuration Overlay not supported 10 1/0 = 48-Bit Address features set supported/not supported 09 0 = Automatic Acoustic Management feature set not enabled 08 0 = SET MAX security extension not enabled by SET MAX SETPASSWORD 07 0 = Reserved	1008h/1408h

	06 0 = SET FEATURES subcommand required to spin-up after power-up not enabled 05 0 = Power-Up in Standby feature set not enabled 04 0 = Obsolete 03 1 = Advanced Power Management feature set enabled 02 0 = CFA feature set not supported 01 0 = READ/WRITE DMA QUEUED Command not supported 00 0 = DOWNLOAD MICROCODE Command not supported	
87	Command set/feature default 15 Shall be cleared to zero 14 Shall be set to one 13 1 = IDLE IMMEDIATE with UNLOAD FEATURE supported 12 0 = Reserved for Technical Report, INCITS TR-37-2004 (TLC) 11 0 = Reserved for Technical Report, INCITS TR-37-2004 (TLC) 10:9 0 = Obsolete 08 0 = 64-Bit World Wide Name not supported 07 0 = WRITE DMA QUEUED FUA EXT Command not supported 06 0 = WRITE DMA FUA EXT and WRITE MULTIPLE FUA EXT commands not supported 05 0 = General Purpose Logging feature set not supported 04 0 = Obsolete 03 0 = Media Card Pass Through Command feature set not supported 02 0 = Media Serial Number is not valid 01 1 = SMART Self-Test supported 00 1 = SMART Error-Logging supported	4003h
88	Ultra DMA modes	007Fh
89	Time required for security erase unit completion	XXXXh
90	Time required for Enhanced security erase unit completion(Not support)	0000h
91	Current advanced power management value	4080h
92	Master Password Revision Code	FFFEh
93	Hardware reset result	600Bh
94-99	Reserved	0000h
100-103	Maximum user LBA for 48-bit Address feature set	XXXXh
104-126	Reserved	0000h
127	Removable Media Status Notification feature set support	0000h
128	Security Status	0001h
129-159	Vendor specific	0000h
160	CFA power mode 1(Not support)	0000h
161-175	Reserved	0000h
176-205	Current media serial number	0000h
206-254	Reserved	0000h
255	CheckSum	XXXXh

5.2.32 Set Features (EFh)

This command is used by the host to establish or select certain features.

5.2.33 Set Features command

This command controls the implementation of various features that the drive supports. When the drive receives this command, it sets BSY, checks the contents of the Features register, clears BSY and generates an interrupt. If the value in the register does not represent a feature that the drive supports, the command is aborted. Power-on default has the read look-ahead and writes caching features enabled. The acceptable values for the Features register are defined as follows:

Table 17: Set features description

Value	Description
01h	Reserved
02h	Enable write cache
03h	Set transfer mode based on value in Sector Count register
04h	Obsolete
05h	Enable advanced power management
06h	Enable Power-Up In Standby feature set.
07h	Power-Up In Standby feature set device spin-up
09h	Reserved
0Ah	Reserved
10h	Reserved for Serial ATA
20h	Reserved
21h	Reserved
31h	Reserved
33h	Obsolete
42h	Reserved
43h	Reserved
44h	Obsolete
54h	Obsolete
55h	Disable read look-ahead feature
5Dh	Reserved
5Eh	Reserved
66h	Disable reverting to power-on defaults
77h	Obsolete
81h	Reserved
82h	Disable write cache
84h	Obsolete
85h	Disable advanced power management
86h	Disable Power-Up In Standby feature set
88h	Obsolete
89h	Reserved
8Ah	Reserved
90h	Reserved for Serial ATA
95h	Reserved
99h	Obsolete
9Ah	Obsolete
AAh	Enable read look-ahead feature
ABh	Obsolete
BBh	Obsolete
C2h	Reserved
CCh	Enable reverting to power-on defaults
DDh	Reserved
DEh	Reserved
E0h	Obsolete
F0-FFh	Reserved

6 Compatibility summary

6.1 Tested Hardware platform versions

The following list indicates the information of platforms which MemoRight tested during the compatibility testing process. The information contains board vendor, chipset/South Bridge and BIOS. The testing process is divided into desktop platform and Notebook platform. At the same time the compatibility testing process is also tested on RAID platforms. The RAID platforms contain the information of RAID SAS Vender, Model and RAID Type.

Note: Please visit www.memoright.com for the latest compatibility list.

6.1.1 Desktop platform

Table 18: Tested Desktop platform Mother Board versions

Board Vendor	Chipset/ South Bridge	BIOS	Remark
ASUS P5B SE	Intel P965/ ICH8	AMI V02.58/0302	Compatible
ASUS P5L-MX	Intel945G/ 82801GB ICH7	AMI 1.18.1083	Compatible
ASUS P5PL2-E	Intel945/ 82801GB ICH7	AMI V02.53/0701	Compatible
ASUS M2A-VM	AMD690G/ SB600	Award 6.00PG/1301	Compatible
ASUS M2S-X	SIS756+965L/ 965L	AMI V02.58/0601	Compatible
ASUS M2V	K8T890/ VT8237A	AMI V02.58/1603	Compatible
ASUS STRIKER680I	NVIDIA680I SLI/ MCP55PXE	Award 6.00PG/0402	Compatible
BIOSTAR TA780G M2+HP	AMD 780G/SB700	Phoenix 080014	Compatible
BIOSTAR TF570SLI	nForce570 LT SLI/ nForce570 LT SLI	Award 6.00PG/A2	Compatible
Color Full P35x	Intel P35/828101B(ICH9)	Award 6.00PG/0409	Compatible
DELL Precision380	Intel955/ 82801GR ICH7R	Phoenix 1.10/A07/A09	Compatible
DELL Optiplex320	ATI RC410(L)/ SB600	Phoenix 1.1.9	Compatible
Foxconn 662MX	SIS662/ 966L	Award 6.00PG/052107	Compatible
GA 73PVM-S2H	nForce7100/ 630I	Award 6.00PG/F2	Compatible
GA MA69VM-S2	AMD690V/ SB600	Award 6.00PG/F2	Compatible
GA X38-DQ6	Intel X38/ Intel82801IB ICH9R	Award 6.00PG/F4	Compatible
MSI 55V2 NEO-F	PT890/ VT8237R+	Award 6.00PG/1.5	Compatible

6.1.2 Notebook platform

Table 19: Tested Notebook platform Mother Board versions

Board Vendor	Chipset/ South Bridge	BIOS	Remark
Dell INSPIRON 9300	Intel i915PM/ ICH6-M	Phoenix A05	Compatible
Dell VOSTRO 1000	ATI RS482/RS485M/ SB600	Phoenix 2.4.1	Compatible
Hp V3625AU	nForce7150M-630 M	Phoenix F.06	Compatible
Mac Book A1181	Intel965@ICH8-DO	Insyde/MB31.88Z.0 08E.0711151547	Compatible
SONY NR12H	Intel 960/ ICH8-D0	Phoenix R0130J9	Compatible

6.1.3 RAID platform

Table 20: Tested RAID Platform

RAID SAS Vendor	Model	Remark
3Ware	9650SE-----4LPML	Compatible
Adaptec	ASR -3805/5405/5805/51645	Compatible
Areca	1280ML /1680i/1680X	Compatible
Areca	1680IX-8/12/16/24	Compatible
Areca	1212/1222	Compatible
Intel	X38-ICH9R / SRCSASJV	Compatible
LSI	LSI 8888	Compatible

6.2 Tested Operating system versions

This list indicates the types of Operating Systems MemoRight tested during the compatibility testing process and highlights the major OS manufacturers. Several variations of the major operating systems have been tested.

Table 21: Tested Operating system versions

Manufacturer	Version	Remark
MAC	OSX 10.4.8, OSX 10.5	Compatible
Microsoft	Windows XP pro CN	Compatible
Microsoft	Windows XP embedded	Compatible
Microsoft	VISTA Home Premium CN	Compatible
Microsoft	Window Server 2003	Compatible
RedHat Linux	Fedora7.0 CN	Compatible

7 COMPLIANCE

MemoRight SATA SSD complies with the requirement listed in the following table.

ROHS

WALTEK SERVICES CO., LTD.
8C, West Tower, Aidi Building, No. 5003 Binhe Rd, Futian District, Shenzhen 518045, China
Tel: 86-755-83551033 83551756 Fax: 86-755-83552400
Http://www.waltek.com.cn E-mail: Info@waltek.com.cn

Determination of Hazardous Substances
TEST REPORT

Report reference No. ..... :	WT08040706-S-R
Date of issue ..... :	2008-04-29
Testing Laboratory ..... :	Waltek Services
Address ..... :	8C, West Tower, Aidi Building, No. 5003 Binhe Rd, Futian District, Shenzhen 518045, China.
Applicant's Name ..... :	MemoRight Memoritech Co., Ltd
Address ..... :	3F., Building W2A, High-Tech Industrial Park, Nanshan District, Shenzhen, China
Description of the appliance ..... :	Solid State Disk
Model and/or type reference ..... :	SATA SSD
Country of Destination ..... :	Europe
Sample Receiving Date ..... :	2008-04-11
Test Conducted ..... :	In accordance with the RoHS Directive 2002/95/EC, and its amendment directives
Conclusion ..... :	All the results in this report are compliant with the limits of RoHS Directive 2002/95/EC and its subsequent amendments
Results ..... :	Refer to next pages

Tested by: Star Song — Star Song

Reviewed by: Akin Xu — Akin Xu

WALTEK TEST REPORT

WALTEK SERVICES
Reference No.: WT08040706-S-R
Page: 1 of 15

WALTEK SERVICES CO., LTD.
8C, West Tower, Aidi Building, No. 5003 Binhe Rd, Futian District, Shenzhen 518045, China.
Tel: 86-755-83551033 83551756 Fax: 86-755-83552400
Http://www.waltek.com.cn E-mail: Info@waltek.com.cn

Test Method: With reference to IEC 62321 Ed.1 111/54/CDV
Procedures for Determination of Levels of Regulated Substances in Electrotechnical Products

(1) Determination of Lead by ICP-AES.

(2) Determination of Cadmium by ICP-AES.

(3) Determination of Mercury by ICP-AES.

(4) Determination of Hexavalent Chromium for non-metallic samples by Ultraviolet and Visible Spectrophotometry

(5) Determination of Hexavalent Chromium for metallic samples by Spot test/ Colorimetric Method

(6) Determination of PBBs and PBDEs by GC/MS

(7) Or combining test reports provided by client.

Remark:
In the following text,
(1) N.D = Not Detected, less than the value of Method Detection Limit
(2) ppm = mg / Kg, based on the dry weight of tested sample
(3) MDL= Method Detection Limit
(4) - - = Not regulated
(5) Lead in glass of cathode ray tube, electronic component and fluorescent tube is exempted by Commission Decision of 21 Oct 2005 Directive 2002/95/EC notified under document 2005/747/EC. This exemption applies to 29th.

All the results are based on the test reports of SGS, CEPREI, LCTECH and CTI, according to client's request.
Refer to the following test reports:
The test reports of SGS: GZ0801007690/CHEM, GZ0703039707/CHEM, SZTYR070309217/LP, SZTYR070412209/LP, GZSCR040935889/LP, GZ0709145550/CHEM, CE/2006/87829, CE/2007/10546, F690501/LF-CTSULP07-00818, LPCI/04153(A)/07, LPCI/23058 (B-2)/06, CE/2007/21186, CE/2007/21169, CE/2008/18527, CE/2008/18520, GZ0610160473/CHEM, GZ0703035953/CHEM, KA/2006/C1614, KA/2006/C1619, JP/2006/020126, KA/2007/20025, KA/2007/20023, KA/2007/20021, KA/2007/20027, KA/2007/20290, KA/2007/20287, KA/2007/20284, KA/2007/20293, KA/2007/20291, KA/2007/20288, KA/2007/20285, KA/2007/20294, KA/2007/20292, KA/2007/20289, KA/2007/20286, KA/2007/20295, F690501/LF-CTSGP06-27864, CE/2006/68140, CE/2006/68141, CE/2006/68143, CE/2006/68144, CE/2006/68148, CE/2006/68151, CE/2006/61928, CE/2006/61929, CE/2007/41196, CE/2007/81736, GZ0706091858/CHEM, CE/2007/35867A, CE/2007/42114, CE/2007/35827, CE/2007/76230, CE/2007/64844, CE/2007/35866, CE/2007/31856, CE/2006/97629, CE/2006/97630, CE/2006/97612, CE/2006/97631, CE/2006/97632, CE/2006/97633, SZTYR060409902/LP, GZ0706081640/CHEM, GZ0703026067/CHEM, GZ0703037164/CHEM, GZ0703026072/CHEM, GZ0703037161/CHEM, EC405825000, SZTYR060202687/LP.
The test report of CEPREI: FX03-2078074.
The test report of LCTECH: LCZS07090083-E.
The test report of CTI: SZR07020611073.

FCC

Reference No.:	**WT07112396-S-F**
Applicant:	**Memoright Memoritech (Shenzhen) Co., Ltd.**
Address:	3/F, Building W2A, High-tech Industrial Park, Nanshan District, Shenzhen, China 518057
Manufacturer:	***Memoright Memoritech (Shenzhen) Co., Ltd.***
Address:	3/F, Building W2A, High-tech Industrial Park, Nanshan District, Shenzhen, China 518057
Product:	**Solid State Disk**
Model No.:	**SATA 2.5 inch**
Technical Data:	**Input: DC 5V 600mA**

The above product has been tested by us with the listed standards and found in Compliance with the Code of Federal Regulations, Title 47-Telecommunications, FCC Rules and Regulations Part 15, Subpart B and the measurement Procedure according to ANSI C63.4:2003. It is possible to use FCC marking to demonstrate the compliance with this FCC Rules.

Conforms to the following FCC Rules Specifications

FCC Part 15.109,Class B-Residential Radiation Emissions at 3 meters. Testing was performed in a FCC Listed 3 meter semi-anechoic chamber.

FCC Part 15.107, Class B-Residential Radiation Emissions at shield Room. Testing was performed in a FCC Listed shield Room.

Supplementary Information:

The product herewith has been successfully tested according to the Code of Federal Regulations, Title 47-Telecommunications.

Test samples were in an engineering configuration.

FCC Confirmation Letter of Authorization for Marketing will be required based On the final product application of the Solid State Disk.

Specific test configurations and results are published in Waltek Services.

Manager
Date: Dec 28, 2007

The statement is based on a single evaluation of the sample of above mentioned products.It does not imply an assessment of the whole production.

WALTEK SERVICES CO.,LTD.
Add: 8C, West Tower, Aidi Building, No.5003 Binhe Rd,Futian District, Shenzhen, China.
Tel: 86-755-83551033 83551756 Fax: 86-755-83552400
Http://www.waltek.com.cn E-mail: info@waltek.com.cn

CE

Declaration of Compliance

Reference No.:	**WT07112395-S-E**
Applicant:	**Memoright Memoritech (Shenzhen) Co., Ltd.**
Address:	3/F, Building W2A, High-tech Industrial Park, Nanshan District, Shenzhen, China 518057
Manufacturer:	**Memoright Memoritech (Shenzhen) Co., Ltd.**
Address:	3/F, Building W2A, High-tech Industrial Park, Nanshan District, Shenzhen, China 518057
Product:	**Solid State Disk**
Model No.:	**SATA 2.5 inch**
Technical Data:	**Input: DC 5V 600mA**

Test Standards:

EN 55022:2006

EN 55024:1998+A2:2003

The above product has been tested by us with the listed standards and found in Compliance with the European Electromagnetic Compatibility Directive 2004/108/EC.It is possible to use CE marking to demonstrate the compliance with this EMC Directive.

EN 55022: Information technology equipment—Radio disturbance characteristics—Limits and methods of measurement
EN 55024: Information technology equipment—Immunity characteristics—Limits and methods of measurement.

The referred test report(s) show that the product complies with standard(s) recognized as giving presumption of compliance with the essential requirements in the above listed EU Directive(s).
Other relevant Directives have to be observed.

After preparation of the necessary technical documentation as well as the conformity declaration the CE marking as shown below can be affixed on the equipment.

Manager
Date: Dec. 28, 2007

CE

The statement is based on a single evaluation of the sample of above mentioned products. It does not imply an assessment of the whole production.

WALTEK SERVICES CO.,LTD.
Add: 8C, West Tower, Aidi Building, No.5003 Binhe Rd,Futian District, Shenzhen, China.
Tel: 86-755-83551033 83551756 Fax: 86-755-83552400
Http:// www.waltek.com.cn E-mail: info@waltek.com.cn

MTBF

ELECTRONICS TESTING CENTER, TAIWAN
ADDRESS: NO.8 LANE 29, WEN-MING RD., LESHAN TSUEN,
GUISHAN SHIANG, TAOYUAN COUNTY 33383, TAIWAN
TEL:03-3280026 FAX:03-3276127
http://www.etc.org.tw

TEST REPORT

Ind. Ser. No. :	08-04-EAT-021-E00
Applicant :	Memoright Memoritech (Shenzhen) Co., Ltd.
Address :	3F, Building W2A, High-Tech Industrial Park, Nanshan District, Shenzhen, China
Commodity :	2.5 inch solid state drive
Model :	MR25.1-S032G
Quantity :	1 set
Date of Receipt :	Mar. 14, 2008
Date of Testing :	Apr. 02, 2008
Ambient Environment :	Temp. 23±5℃, R.H. 60±10%
Testing Item :	

MTBF (Mean-Time-Between-Failure) prediction

Approved by Andrew Y Lin

ELECTRONICS TESTING CENTER TAIWAN USE FOR TESTING REPORT ONLY ELECTRONICS TESTING DEPARTMENT

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ETC

TEST REPORT

Ind. Ser. No. 08-04-EAT-021-E00

Testing Conditions : According to applicant's specifications

Calculation model : Telcordia SR-332 Issue 1

Method 1, Case 1

Operating environment : GB, Temperature: 25.0 °C,

Testing Equipments :

Name	CONTENT
BOM, bill of materials	Memoright Memoritech (Shenzhen) Co., Ltd. supplied
Authorized reliability prediction software	Relex reliability software V7.7

Testing Results :

Date of testing : Apr. 02, 2008

Failure Rate : 0.864205 Failures/10^6 Hours

MTBF : 1,157,132Hours

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8 Ordering Information

MemoRight SSD Product Model Name:

Example: **MR25.2-032S**

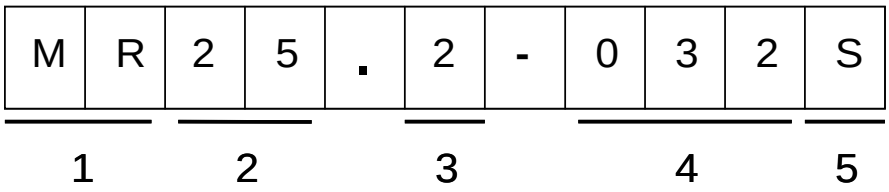

Figure 3.Ordering Information

1: **MR**: stand for MemoRight

2: Mechanical dimension

35: 3.5 inch

25: 2.5 inch

18: 1.8 inch

3: Generation of this product

1: Generation 1

2: Generation 2

4: Capacity of disk in GB

032: 32 GBytes

064: 64 GBytes

128: 128 GBytes

5: Interface of disk

A: ATA type

S: SATA type

9 MemoRight support services

Product Quality Assurance

It is guaranteed that the products are produced strictly in accordance with IS09001 standard. All selling products have been measured using specific testing systems. The quality, specification and performance of the products shall be in the same as the specification.

After service

If the MemoRight's NSSD products conk out within 5 years under the proper operation, the users will be offered maintenance service.

Contact information

To order or obtain information on pricing and delivery, please contact with your local MemoRight sales representative or distributor, or visit our website:www.memoright.com to obtain the latest specifications before placing your order.

Table 22: Contact information

Telephone	86-0755-26520558
Fax	86-0755-26616825
Web	www.memoright.com
Headquarters Address	3/F,Building W2A,High-tech Industrial Park,Nanshan District,Shenzhen,China518057

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